

SCRs

.5 Amp, Planar

ID100-ID106

FEATURES

- Voltage Ratings: to 400V
- Maximum Gate Trigger Current: 200 μ A
- Hermetically Sealed TO-18 Metal Can
- Planar Passivated Construction

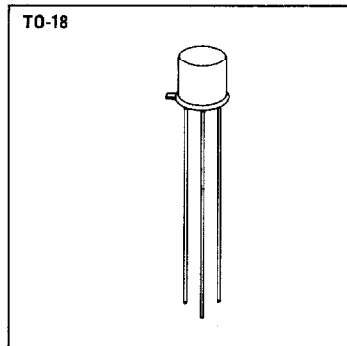
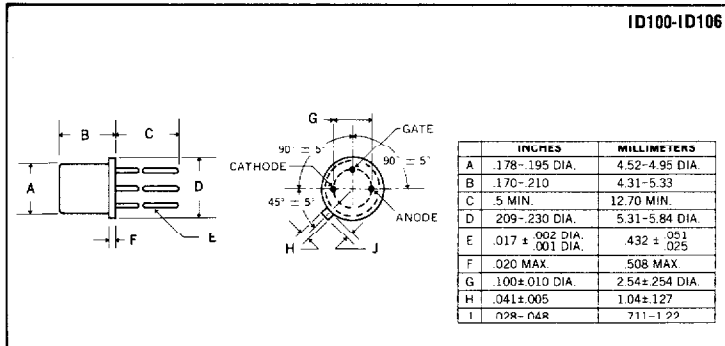
DESCRIPTION

This Data Sheet describes Microsemi's line of hermetically sealed industrial SCRs designed for low-voltage, low-current sensing application. The ID100 Series is packaged in a TO-18 metal case with Microsemi's unique oxide passivated junctions, offering the highest degree of reliability and parameter stability for any device in its price range. Typical applications include lamp driving, relay driving, sensor, pulse-generating and timing circuits.

ABSOLUTE MAXIMUM RATINGS

| | ID100 | ID101 | ID102 | ID103 | ID104 | ID105 | ID106 |
|---|-----------------|-------|-------|-------|-------|-------|-------|
| Repetitive Peak Off-State Voltage, V_{DRM} | 30V | 60V | 100V | 150V | 200V | 300V | 400V |
| Repetitive Peak Reverse Voltage, V_{RRM} | 30V | 60V | 100V | 150V | 200V | 300V | 400V |
| On-State Current, I_T | | | | | | | |
| 75°C Ambient | 250mA | | | | | | |
| 100°C Case | 0.5A | | | | | | |
| Repetitive Peak On-State Current, I_{TRM} | 6A | | | | | | |
| Peak One Cycle Surge (Non-Rep.) On-State Current, I_{TSM} | up to 30A | | | | | | |
| Peak Gate Current, I_{GM} | 250mA | | | | | | |
| Average Gate Current, $I_{G(AV)}$ | 25mA | | | | | | |
| Reverse Gate Voltage, V_{GR} | 6V | | | | | | |
| Storage Temperature Range | -65°C to +150°C | | | | | | |
| Operating Temperature Range | -65°C to +125°C | | | | | | |

MECHANICAL SPECIFICATIONS



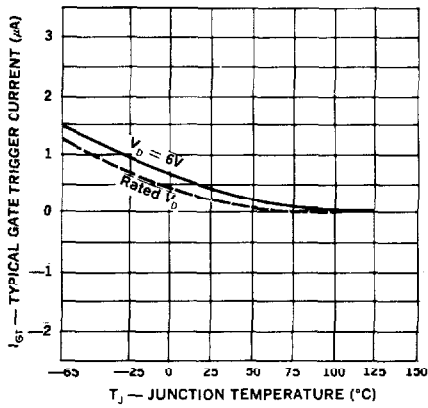
ELECTRICAL SPECIFICATIONS (at 25°C unless noted)

| Test | Symbol | Min. | Typical | Max. | Units | Test Conditions |
|----------------------------------|-----------|-------------|-------------|-------------|--------------------|--|
| Off-State Current | I_{DRM} | — | 5.0 10.0 | 50 100 | μA μA | $V_{DRM} = \text{Rating}, R_{GK} = 1K, T = 125^\circ C, ID100-ID104$ $V_{DRM} = \text{Rating}, R_{GK} = 1K, T = 125^\circ C, ID105-ID106$ |
| Reversing Current | I_{RRM} | — | 10 15 | 50 100 | μA μA | $V_{RRM} = \text{Rating}, R_{GK} = 1K, T = 125^\circ C, ID100-ID104$ $V_{RRM} = \text{Rating}, R_{GK} = 1K, T = 125^\circ C, ID105-ID106$ |
| Gate Trigger Current | I_{GT} | — | 5.0 | 200 | μA | $V_D = 5V, R_{GS} = 10K$ $V_D = 5V, R_{GS} = 10K, T = -40^\circ C$ |
| Gate Trigger Voltage | V_{G1} | 0.4 0.10 | 0.55 | 0.8 1.0 | V V | $V_D = 5V, R_{GS} = 100\Omega$ $V_D = 5V, R_{GS} = 100\Omega, T = -40^\circ C$ $V_D = 5V, R_{GS} = 100\Omega, T = 125^\circ C$ |
| Peak On-State Voltage | V_{TM} | — | — | 1.7 | V | $I_{TM} = 1 \text{ Amp Pulse}$ |
| Holding Current | I_H | — | 1.0 | 5.0 10.0 | mA mA | $R_{GK} = 1K$ $R_{GK} = 1K, T = -40^\circ C$ |
| Turn-on Time | t_{on} | — | 0.5 | — | μs | $I_G = 10mA, I_T = 1A, V_D = 30V$ |
| Circuit Commutated Turn-off Time | t_q | — | 8.0 | — | μs | $I_T = I_R = 1A, R_{GK} = 1K, ID100-ID104$ $I_T = I_R = 1A, R_{GK} = 1K, ID105-ID106$ |

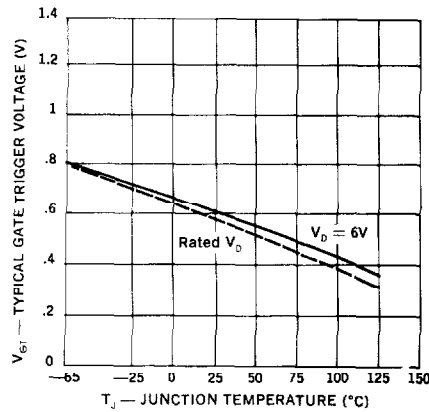
Note: Blocking voltage ratings apply over the full operating temperature range, provided the gate is connected to the cathode through a resistor, 1000 ohms or smaller, or other adequate bias is used.



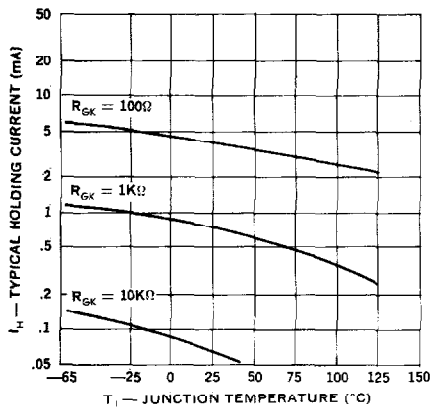
Gate Trigger Current vs. Junction Temp.



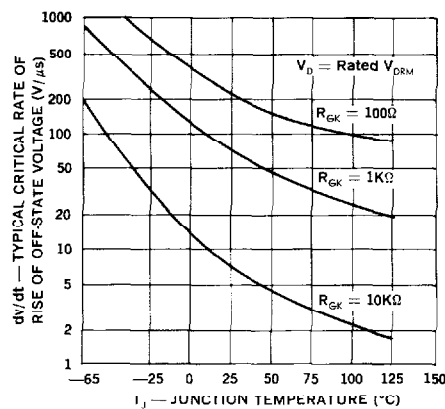
Gate Trigger Voltage vs. Junction Temp.



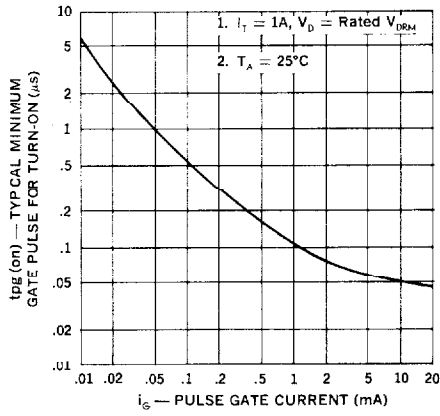
Holding Current vs. Junction Temp.



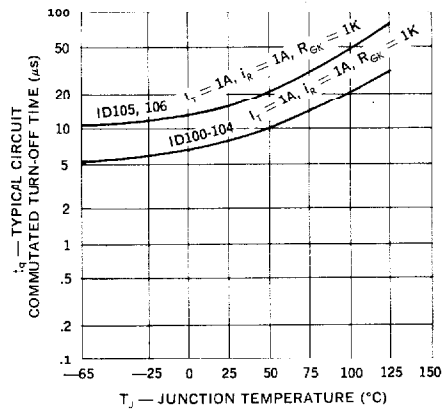
dv/dt vs. Junction Temp.



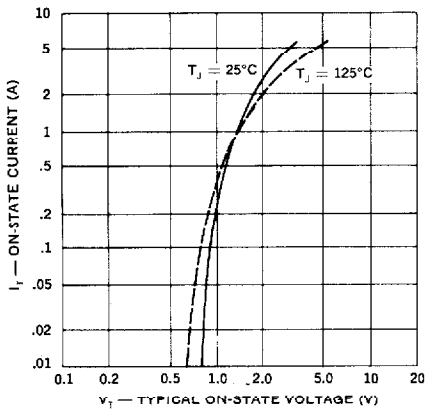
Gate Pulse for Turn-On vs. Pulse Gate Current



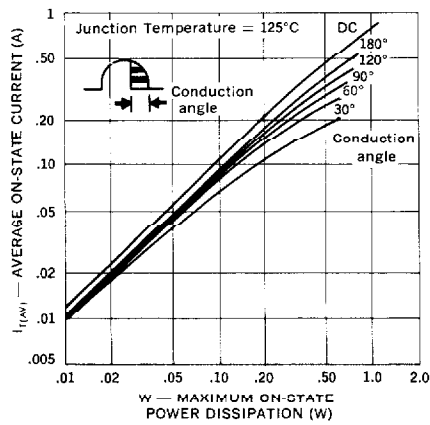
Circuit Commutated Turn-Off Time vs. Junction Temp.



Current vs. On State Voltage



Current vs. Power Dissipation





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